



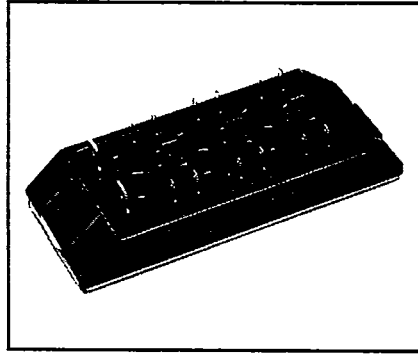
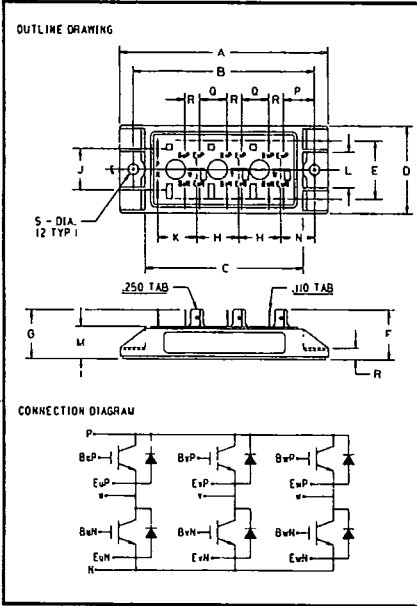
IEF260A2

T-39-31

Powerex, Inc., Hillis Street, Youngwood, Pennsylvania 15697 (412) 925-7272
 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

**Six-IGBT IGBTMOD™
 Power Module**

25 Amperes/600 Volts



**IEF260A2
 Six-IGBT IGBTMOD™ Power Module
 25 Amperes/600 Volts**

**IEF260A2
 Outline Drawing**

Dimension	Inches	Millimeters
A	4.21	107
B	3.66±.01	93±0.3
C	3.19	81
D	1.77	45
E	1.18	30
F	1.04	26.5
G	1.01	25.6
H	.85	21.5
J	.83	21
K	.79	20
L	.71	18
M	.69±.02	17.5±0.5
N	.69	17.5
P	.63	16
Q	.55	14
R	.30	7.5
S	.22 Dia.	Dia. 5.5

Description

Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of six IGBT Transistors in a three phase bridge configuration, with each transistor having a reverse-connected super-fast recovery free wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

Features:

- Low Drive Power
- Low $V_{CE(sat)}$
- Discrete Super-Fast Recovery (150ns) Free Wheel Diode
- High Frequency Operation (15-20kHz)
- Isolated Base Plate for Easy Heat Sinking

Applications:

- AC Motor Control
- Motion/Servo Control
- UPS
- Welding Power Supplies
- Laser Power Supplies

Ordering Information

Example: Select the complete eight digit part module number you desire from the table below -i.e. IEF260A2 is a 600V (V_{CES}), 25 Ampere Six-IGBT IGBTMOD™ Power Module.

Type	V_{CES} Volts (x10)	Current Rating Amperes (25)
IEF2	60	A2



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Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	IEF260A2	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Voltage (G-E SHORT)	V_{CES}	600	Volts
Gate-Emitter Voltage	V_{GES}	± 20	Volts
Collector Current	I_C	25	Amperes
Peak Collector Current	I_{CM}	50*	Amperes
Diode Forward Current	I_{FM}	25	Amperes
Diode Forward Surge Current	I_{FM}	50*	Amperes
Power Dissipation	P_d	150	Watts
Max. Mounting Torque M5 Terminal Screws	—	—	in.-lb.
Max. Mounting Torque M6 Mounting Screws	—	17	in.-lb.
Module Weight (Typical)	—	260	Grams
V isolation	V_{RMS}	2500	Volts

* Pulse width and repetition rate should be such that device junction temperature does not exceed the device rating.

Static Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Cutoff Current	I_{CES}	$V_{CE}=V_{CES}, V_{GE}=0V$	—	—	1.0	mA
Gate Leakage Current	I_{GES}	$V_{GE}=V_{GES}, V_{CE}=0V$	—	—	0.5	μA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$I_C=2.5\text{mA}, V_{CE}=10V$	3.0	4.0	6.0	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=25A, V_{GE}=15V$	—	3.0	5.0**	Volts
		$I_C=25A, V_{GE}=15V, T_j=150^\circ\text{C}$	—	3.2	**	Volts
Total Gate Charge	Q_G	$V_{CC}=300V, I_C=25A, V_{GS}=15V$	—	80	—	nC
Diode Forward Voltage	V_{FM}	$I_C=-25A, V_{GS}=0V$	—	—	2.5	Volts

** Pulse width and repetition rate should be such that device junction temperature rise is negligible

Dynamic Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Input Capacitance	C_{ies}	—	—	—	2500	pF
Output Capacitance	C_{oes}	$V_{GE}=0V, V_{CE}=10V, f=1\text{MHz}$	—	—	600	pF
Reverse Transfer Capacitance	C_{res}	—	—	—	60	pF
Resistive Load	Turn-on Delay Time	$V_{CC}=300V, I_C=25A,$	—	—	250	ns
	Rise Time					
Switch Times	Turn-off Delay Time	$V_{GE1}=V_{GE2}=15V, R_G=100\Omega$	—	—	600	ns
	Fall Time					
Diode Reverse Recovery Time	t_{rr}	$I_E=25A, di_E/dt=-50A/\mu\text{s}$	—	—	200	ns
Diode Reverse Recovery Charge	Q_{rr}	$I_E=25A, di_E/dt=-50A/\mu\text{s}$	—	0.3	—	μC

Thermal and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

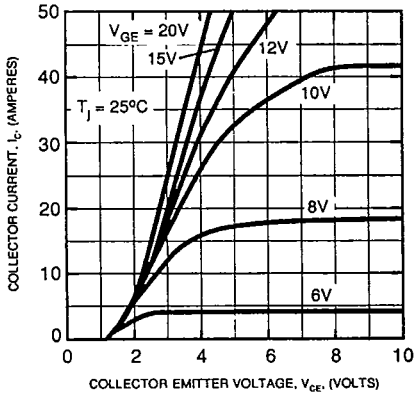
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	Per IGBT	—	—	0.80	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	Per Free Wheel Diode	—	—	2.00	$^\circ\text{C}/\text{W}$
Contact Thermal Resistance	$R_{th(c-f)}$	Per 1/6 Module	—	—	0.35	$^\circ\text{C}/\text{W}$



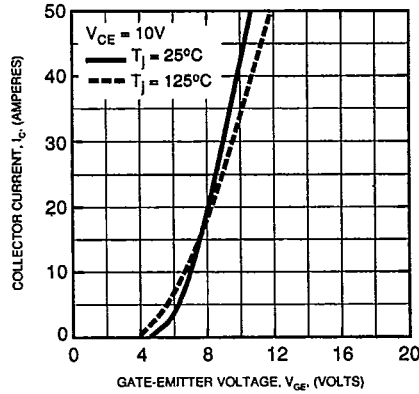
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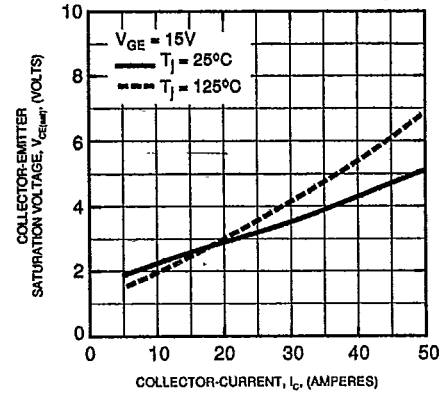
OUTPUT CHARACTERISTICS (TYPICAL)



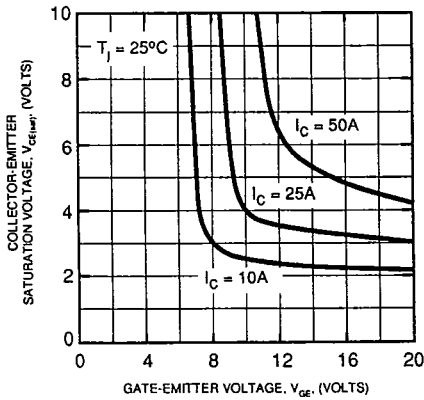
TRANSFER CHARACTERISTICS (TYPICAL)



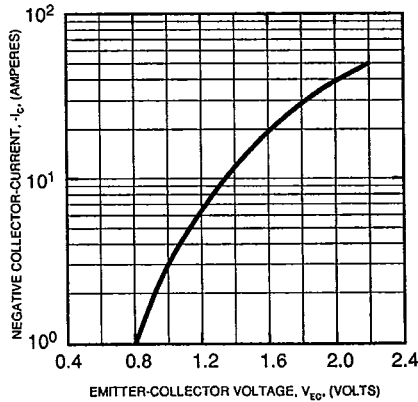
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



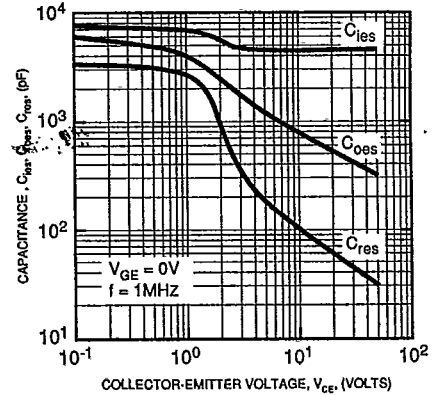
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



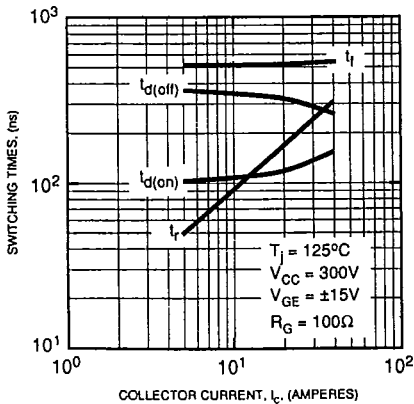
FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



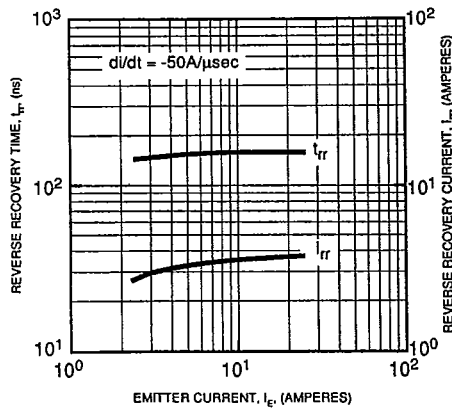
CAPACITANCE VS. V_{CE} (TYPICAL)



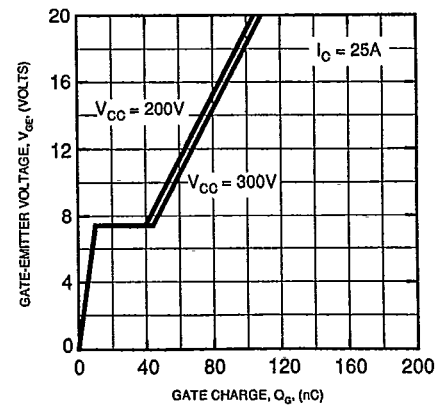
HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (TYPICAL)



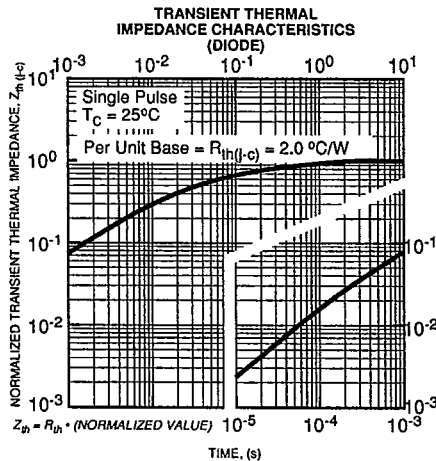
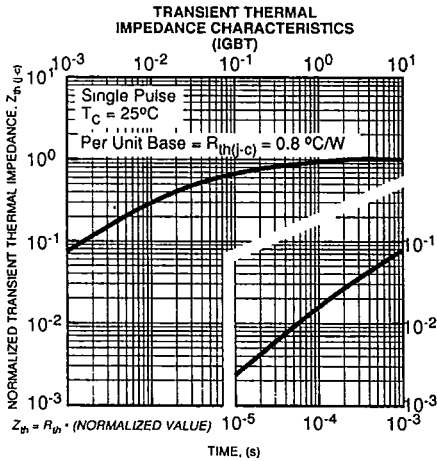
GATE CHARGE, V_{GE}



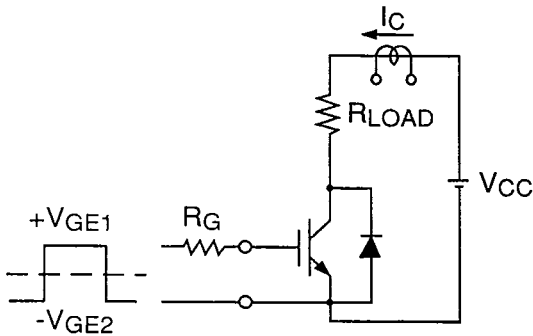


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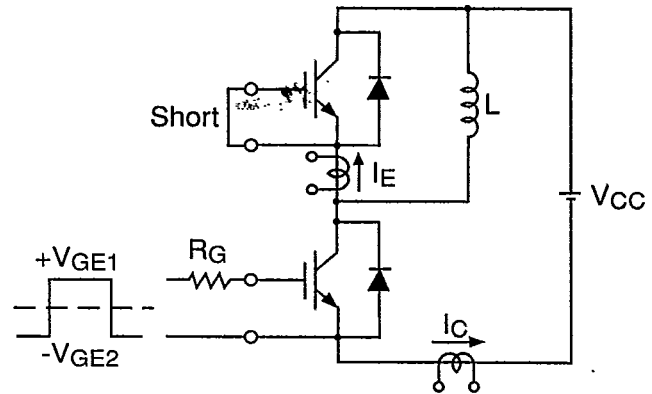
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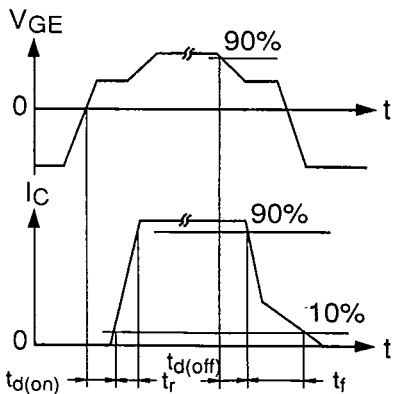
SWITCHING TIME TEST CIRCUITS & WAVEFORMS



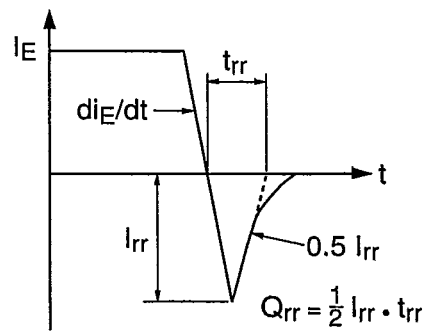
Resistance Load Switching Test Circuit



Half-Bridge Switching Test Circuit



Switching Time Test Waveforms



trr, Qrr Waveforms